FDS9926A

-AIRCHILD

Dual N-Channel 2.5V Specified PowerTrench[®] MOSFET

General Description

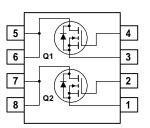
These N-Channel 2.5V specified MOSFETs use Fairchild Semiconductor's advanced PowerTrench process. It has been optimized for power management applications with a wide range of gate drive voltage (2.5V - 10V).

Applications

- Battery protection
- Load switch
- Power management



- 6.5 A, 20 V. $R_{DS(ON)} = 0.030 \ \Omega \ @ V_{GS} = 4.5 \ V$ $R_{DS(ON)} = 0.043 \ \Omega \ @ V_{GS} = 2.5 \ V.$
- Optimized for use in battery protection circuits
- + $\pm 10 V_{GSS}$ allows for wide operating voltage range
- Low gate charge



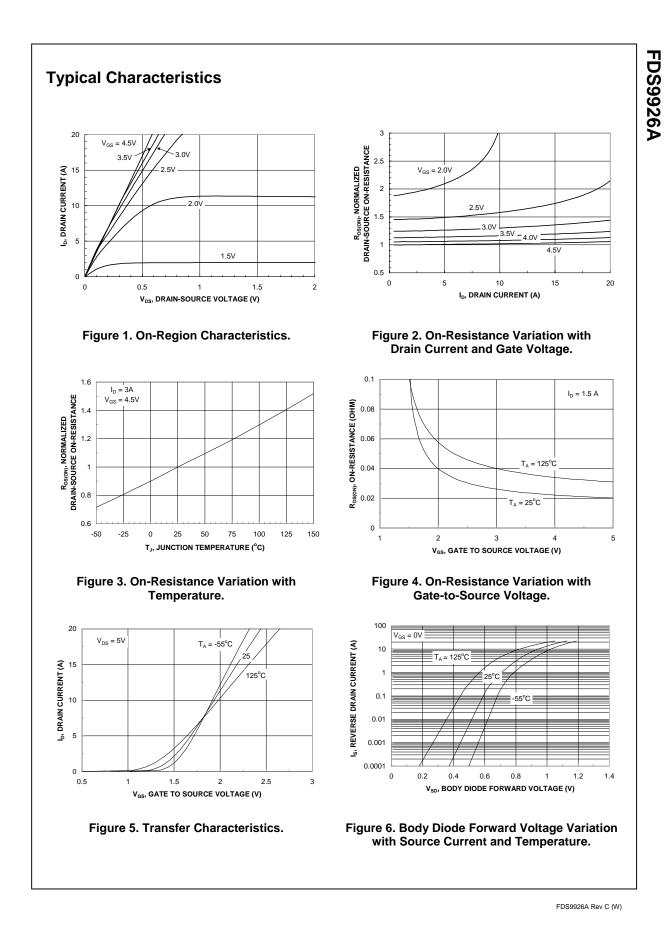
Absolute Maximum Ratings T_A=25°C unless otherwise noted

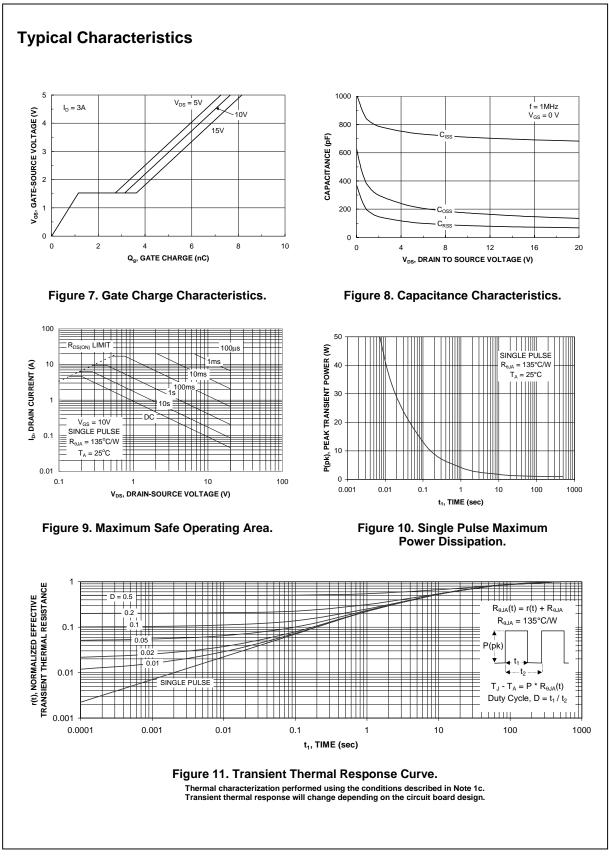
Symbol		Parameter	Ratings	Units	
V _{DSS}	Drain-Sourc	e Voltage		20	V
V _{GSS}	Gate-Source Voltage			±10	V
I _D	Drain Current – Continuous (Note 1a)		(Note 1a)	6.5	A
		– Pulsed		20	
P _D	Power Dissipation for Dual Operation			2	W
	Power Dissi	pation for Single Operatior	n (Note 1a)	1.6	
			(Note 1b)	1	
			(Note 1c)	0.9	
T _J , T _{STG}	Operating and Storage Junction Temperature Range			-55 to +150	°C
Therma	I Charact	eristics			
R _{θJA}	Thermal Resistance, Junction-to-Ambient (Note 1a)			78	°C/W
R _{θJC}	Thermal Resistance, Junction-to-Case (Note 1)			40	°C/W
Packag	e Marking	g and Ordering l	nformation		
Device Marking		Device	Reel Size	Tape width	Quantity
FDS9926A		FDS9926A	13"	12mm	2500 units

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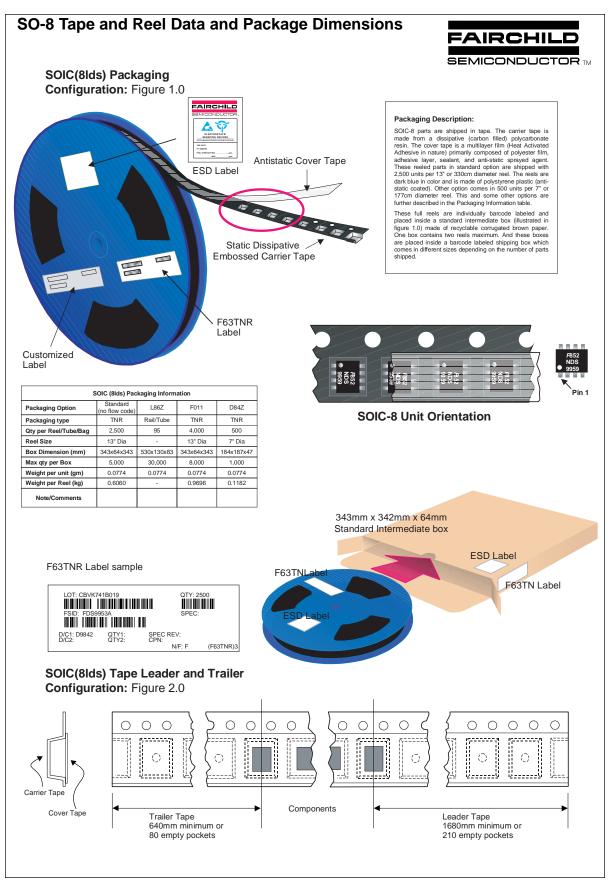
FDS9926A

$\begin{array}{l} V_{GS} = 0 \ V, \ I_{D} = 250 \ \mu A \\ I_{D} = 250 \ \mu A, \ Referenced \ to \ 25^{\circ}C \\ V_{DS} = 16 \ V, V_{GS} = 0 \ V \\ V_{GS} = 8 \ V, V_{DS} = 0 \ V \\ V_{GS} = -8 \ V V_{DS} = 0 \ V \\ \end{array}$	0.5	14	1 100 -100 1.5	V mV/°C μA nA NA		
$\begin{split} I_{D} &= 250 \; \mu\text{A}, \text{Referenced to } 25^{\circ}\text{C} \\ V_{DS} &= 16 \; \text{V}, V_{GS} &= 0 \; \text{V} \\ V_{GS} &= 8 \; \text{V}, V_{DS} &= 0 \; \text{V} \\ V_{GS} &= -8 \; \text{V} V_{DS} &= 0 \; \text{V} \\ \end{split} \\ \end{split} \\ \begin{split} V_{DS} &= V_{GS}, \; I_{D} &= 250 \; \mu\text{A} \\ I_{D} &= 250 \; \mu\text{A}, \; \text{Referenced to } 25^{\circ}\text{C} \\ V_{GS} &= 4.5 \; \text{V}, I_{D} &= 6.5 \; \text{A} \\ V_{GS} &= 2.5 \; \text{V}, I_{D} &= 5.4 \; \text{A} \\ V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{S} &= 6.5 \; \text{A}, \; V_{S} &= 6.5 \; \text{A}, \; V_{S$		1	100 -100	mV/°C μA nA nA		
$\begin{split} I_{D} &= 250 \; \mu\text{A}, \text{Referenced to } 25^{\circ}\text{C} \\ V_{DS} &= 16 \; \text{V}, V_{GS} &= 0 \; \text{V} \\ V_{GS} &= 8 \; \text{V}, V_{DS} &= 0 \; \text{V} \\ V_{GS} &= -8 \; \text{V} V_{DS} &= 0 \; \text{V} \\ \end{split} \\ \end{split} \\ \begin{split} V_{DS} &= V_{GS}, \; I_{D} &= 250 \; \mu\text{A} \\ I_{D} &= 250 \; \mu\text{A}, \; \text{Referenced to } 25^{\circ}\text{C} \\ V_{GS} &= 4.5 \; \text{V}, I_{D} &= 6.5 \; \text{A} \\ V_{GS} &= 2.5 \; \text{V}, I_{D} &= 5.4 \; \text{A} \\ V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{D} &= 6.5 \; \text{A}, \; V_{GS} &= 4.5 \; \text{V}, \; I_{S} &= 6.5 \; \text{A}, \; V_{S} &= 6.5 \; \text{A}, \; V_{S$	0.5	1	100 -100	μA nA nA		
$\begin{split} V_{DS} &= 16 \ V, \qquad V_{GS} = 0 \ V \\ V_{GS} &= 8 \ V, \qquad V_{DS} = 0 \ V \\ V_{GS} &= -8 \ V \qquad V_{DS} = 0 \ V \\ \end{split} \\ \end{split} \\ \begin{array}{l} V_{DS} &= -8 \ V \qquad V_{DS} = 0 \ V \\ \end{array} \\ \hline V_{DS} &= 250 \ \mu A, \ Referenced \ to \ 25^{\circ}C \\ \hline V_{GS} &= 4.5 \ V, I_D = 6.5 \ A \\ V_{GS} &= 2.5 \ V, I_D = 5.4 \ A \\ V_{GS} &= 4.5 \ V, \ I_D = 6.5A, \ T_J = 125^{\circ}C \\ \end{split}$	0.5	1	100 -100	μA nA nA		
$\begin{split} V_{GS} &= 8 \ V, \qquad V_{DS} = 0 \ V \\ V_{GS} &= -8 \ V \qquad V_{DS} = 0 \ V \\ \end{split} \\ \hline V_{DS} &= V_{GS}, \ I_D = 250 \ \mu A \\ I_D &= 250 \ \mu A, \ Referenced \ to \ 25^\circ C \\ \hline V_{GS} &= 4.5 \ V, \qquad I_D = 6.5 \ A \\ V_{GS} &= 2.5 \ V, \qquad I_D = 5.4 \ A \\ V_{GS} &= 4.5 \ V, \ I_D = 6.5A, \ T_J = 125^\circ C \end{split}$	0.5		100 -100	nA nA		
$\begin{split} V_{GS} &= -8 \ V & V_{DS} = 0 \ V \\ \hline V_{DS} &= V_{GS}, \ I_D = 250 \ \mu A \\ \hline I_D &= 250 \ \mu A, \ Referenced \ to \ 25^\circ C \\ \hline V_{GS} &= 4.5 \ V, I_D = 6.5 \ A \\ \hline V_{GS} &= 2.5 \ V, I_D = 5.4 \ A \\ \hline V_{GS} &= 4.5 \ V, \ I_D = 6.5A, \ T_J = 125^\circ C \end{split}$	0.5		-100	nA		
$\begin{split} V_{DS} &= V_{GS}, \ I_D = 250 \ \mu A \\ I_D &= 250 \ \mu A, \ Referenced \ to \ 25^\circ C \\ V_{GS} &= 4.5 \ V, I_D = 6.5 \ A \\ V_{GS} &= 2.5 \ V, I_D = 5.4 \ A \\ V_{GS} &= 4.5 \ V, \ I_D = 6.5A, \ T_J = 125^\circ C \end{split}$	0.5		I			
$\begin{split} I_D &= 250 \; \mu\text{A}, \; \text{Referenced to} \; 25^\circ\text{C} \\ V_{GS} &= 4.5 \; \text{V}, I_D &= 6.5 \; \text{A} \\ V_{GS} &= 2.5 \; \text{V}, I_D &= 5.4 \; \text{A} \\ V_{GS} &= 4.5 \; \text{V}, \; I_D &= 6.5 \text{A}, \; T_J &= 125^\circ\text{C} \end{split}$	0.5		1.5	V		
$\begin{split} I_D &= 250 \; \mu\text{A}, \; \text{Referenced to} \; 25^\circ\text{C} \\ V_{GS} &= 4.5 \; \text{V}, I_D &= 6.5 \; \text{A} \\ V_{GS} &= 2.5 \; \text{V}, I_D &= 5.4 \; \text{A} \\ V_{GS} &= 4.5 \; \text{V}, \; I_D &= 6.5 \text{A}, \; T_J &= 125^\circ\text{C} \end{split}$	0.5		1.5	V		
$ \begin{array}{l} V_{GS} = 4.5 \ V, & I_D = 6.5 \ A \\ V_{GS} = 2.5 \ V, & I_D = 5.4 \ A \\ V_{GS} = 4.5 \ V, \ I_D = 6.5A, \ T_J = 125^\circ C \end{array} $		-3				
$V_{GS} = 2.5 V$, $I_D = 5.4 A$ $V_{GS} = 4.5 V$, $I_D = 6.5 A$, $T_J = 125^{\circ}C$				mV/°C		
V_{GS} = 4.5 V, I _D =6.5A, T _J =125°C		0.025 0.036	0.030 0.043	Ω		
$V_{cc} = 45 V$ $V_{bc} = 5 V$		0.035	0.050			
$v_{GS} = 4.0 v_{1}$, $v_{DS} = 0 v_{1}$	15			А		
$V_{DS} = 5 V$, $I_D = 3 A$		11		S		
			•			
y' = 10y' = y' = 0y'		700		pF		
f = 1.0 MHz				pF		
		-		pF		
		00		Pi		
1	1	1				
		-	-	ns		
		10		ns		
		18	29	ns		
		5	10	ns		
		7	10	nC		
		1.2		nC		
		1.9		nC		
and Maximum Ratings						
Maximum Continuous Drain–Source Diode Forward Current 1.3 A						
$V_{GS} = 0 V$, $I_S = 1.3 A$ (Note 2)		0.65	1.2	V		
	$V_{DD} = 10 \text{ V}, \qquad I_D = 1 \text{ A}, \\ V_{GS} = 4.5 \text{ V}, \qquad R_{GEN} = 6 \Omega$ $V_{DS} = 10 \text{ V}, \qquad I_D = 3\text{ A}, \\ V_{GS} = 4.5 \text{ V}$ and Maximum Ratings Diode Forward Current $V_{GS} = 0 \text{ V}, I_S = 1.3 \text{ A} (\text{Note 2})$	$f = 1.0 \text{ MHz}$ $V_{DD} = 10 \text{ V}, I_D = 1 \text{ A},$ $V_{GS} = 4.5 \text{ V}, R_{GEN} = 6 \Omega$ $V_{DS} = 10 \text{ V}, I_D = 3\text{ A},$ $V_{GS} = 4.5 \text{ V}$ and Maximum Ratings Diode Forward Current	$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $		

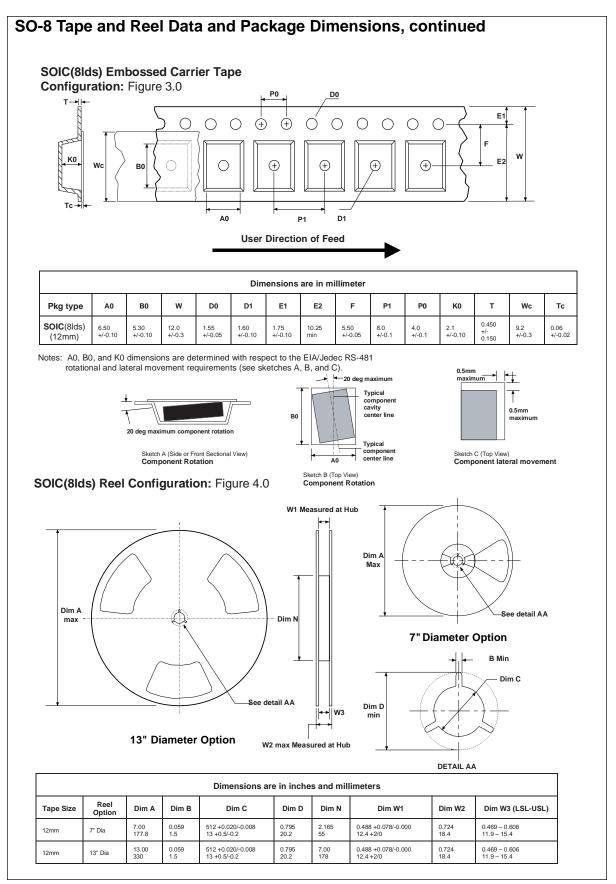


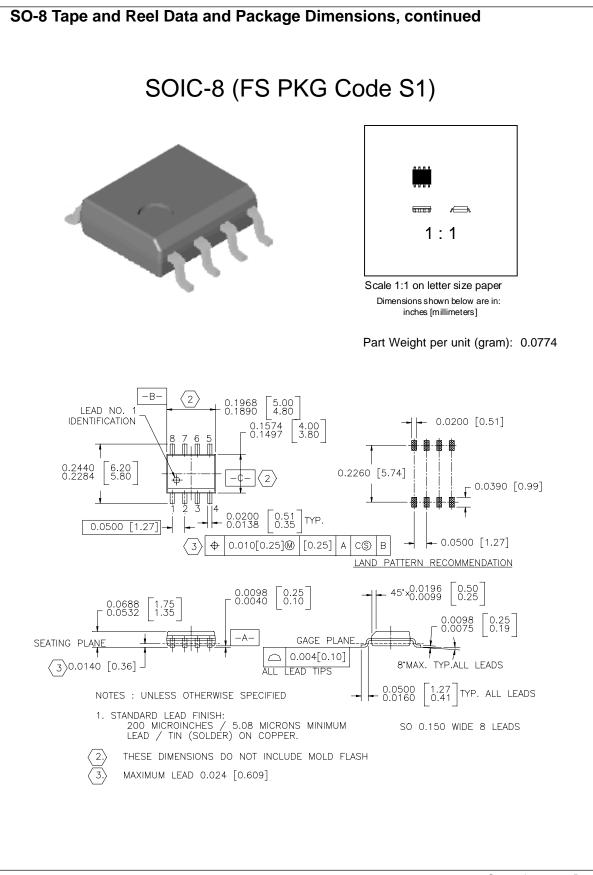


FDS9926A



July 1999, Rev. B





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